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#### Discrete POWER & Signal **Technologies**

## 2N5962

## **MMBT5962**





## **NPN General Purpose Amplifier**

This device is designed for use as low noise, high gain, general purpose amplifiers requiring collector currents to 50 mA. Sourced from Process 07. See 2N5088 for characteristics.

### **Absolute Maximum Ratings\***

TA = 25°C unless otherwise noted

| Symbol                            | Parameter  | Value       | Units |  |  |
|-----------------------------------|--|-------------|-------|--|--|
| $V_{CEO}$                         | Collector-Emitter Voltage                        | 45          | V     |  |  |
| V <sub>CBO</sub>                  | Collector-Base Voltage                           | 45          | V     |  |  |
| V <sub>EBO</sub>                  | Emitter-Base Voltage                             | 8.0         | V     |  |  |
| I <sub>C</sub>                    | Collector Current - Continuous                   | 100         | mA    |  |  |
| T <sub>J</sub> , T <sub>stg</sub> | Operating and Storage Junction Temperature Range | -55 to +150 | °C    |  |  |

<sup>\*</sup>These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### **Thermal Characteristics**

TA = 25°C unless otherwise noted

| Symbol          | Characteristic                             | М          | Units      |             |
|-----------------|--|------------|------------|-------------|
|                 |  | 2N5962     | *MMBT5962  |             |
| P <sub>D</sub>  | Total Device Dissipation Derate above 25°C | 625<br>5.0 | 350<br>2.8 | mW<br>mW/°C |
| $R_{\theta JC}$ | Thermal Resistance, Junction to Case       | 83.3       |            | °C/W        |
| $R_{\theta JA}$ | Thermal Resistance, Junction to Ambient    | 200        | 357        | °C/W        |

<sup>\*</sup>Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.

2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

## NPN General Purpose Amplifier (continued)

| Symbol               | Parameter  | Test Conditions   | Min        | Max               | Units    |
|----------------------|--|---|------------|-------------------|----------|
|                      |  |   |            |                   |          |
| OFF CHA              | RACTERISTICS                                       |   |            |                   |          |
| $V_{(BR)CEO}$        | Collector-Emitter Breakdown Voltage*               | $I_{\rm C} = 5.0 \text{ mA}, I_{\rm B} = 0$   | 45         |                   | V        |
| $V_{(BR)CBO}$        | Collector-Base Breakdown Voltage                   | $I_{\rm C} = 10  \mu \text{A}, I_{\rm E} = 0$   | 45         |                   | V        |
| $V_{(BR)EBO}$        | Emitter-Base Breakdown Voltage                     | $I_E = 10  \mu A, I_C = 0$  | 8.0        |                   | V        |
| I <sub>CBO</sub>     | Collector Cutoff Current                           | $V_{CB} = 30 \text{ V}, I_{E} = 0$  |            | 2.0               | nA       |
| ı                    | Emitter Cutoff Current                             | $V_{CB} = 30 \text{ V}, I_{E} = 0, T_{A} = 65 ^{\circ}\text{C}$<br>$V_{EB} = 5.0 \text{ V}, I_{C} = 0$  |            | 50<br>1.0         | nA<br>nA |
| l <sub>EBO</sub>     | Emiller Culon Current                              | V <sub>EB</sub> - 5.0 V, I <sub>C</sub> - 0   |            | 1.0               | ПА       |
|                      |  |   |            |                   |          |
| ON CHAF              | RACTERISTICS*                                      |   |            |                   | _        |
| h <sub>FE</sub>      | DC Current Gain                                    | $V_{CE} = 5.0 \text{ V}, I_{C} = 10 \mu\text{A}$  | 450        |                   |          |
|                      |  | $V_{CE} = 5.0 \text{ V}, I_{C} = 100 \mu\text{A}$   | 500<br>550 |                   |          |
|                      |  | $V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$<br>$V_{CE} = 5.0 \text{ V}, I_{C} = 10 \text{ mA}$   | 600        | 1400              |          |
| V <sub>CE(sat)</sub> | Collector-Emitter Saturation Voltage               | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0.5 \text{ mA}$   |            | 0.2               | V        |
| V <sub>BE(on)</sub>  | Base-Emitter On Voltage                            | $V_{CE} = 5.0 \text{ V}, I_{C} = 1.0 \text{ mA}$  | 0.5        | 0,7               | V        |
| C <sub>cb</sub>      | GIGNAL CHARACTERISTICS  Collector-Base Capacitance | V <sub>CB</sub> = 5.0 V   | <u> </u>   | 4.0               | pF       |
| C <sub>eb</sub>      | Emitter-Base Capacitance                           | V <sub>EB</sub> = 0.5 V   |            | 6.0               | pF       |
| h <sub>fe</sub>      | Small-Signal Current Gain                          | 1 40 4 14 5 0 14  |            |                   |          |
|                      |  | $I_{\rm C}$ = 10 mA, $V_{\rm CE}$ = 5.0 V,  |            |                   |          |
|                      |  | f = 1.0 kHz   | 600        | 200               | <u> </u> |
|                      |  | f = 1.0  kHz<br>$I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$  |            | 200               | F.       |
| NF                   | Noise Figure                                       | f = 1.0 kHz   | 600<br>1.0 | 200               |          |
| NF                   | Noise Figure                                       | f = 1.0  kHz<br>$I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V},$<br>f = 100  MHz  |            |                   |          |
| NF                   | Noise Figure                                       | $\begin{array}{l} f = 1.0 \text{ kHz} \\ I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \hline V_{CE} = 5.0 \text{ V}, I_C = 10 \mu\text{A}, \\ R_S = 10 k\Omega, f = 1.0 k\text{Hz}, \\ B_W = 400 \text{ Hz} \\ \end{array}$   |            | 200<br>3.0        | dB       |
| NF                   | Noise Figure                                       | $\begin{array}{l} f = 1.0 \text{ kHz} \\ I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \hline V_{CE} = 5.0 \text{ V}, I_C = 10 \mu\text{A}, \\ R_S = 10 k\Omega, f = 1.0 k\text{Hz}, \\ B_W = 400 \text{ Hz} \\ V_{CE} = 5.0 \text{ V}, I_C = 100 \mu\text{A}, \end{array}$  |            |                   |          |
| NF                   | Noise Figure                                       | $\begin{array}{l} f = 1.0 \text{ kHz} \\ I_C = 10 \text{ mA}, \ V_{CE} = 5.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \\ V_{CE} = 5.0 \text{ V}, \ I_C = 10 \mu\text{A}, \\ R_S = 10 k\Omega, \ \ f = 1.0 \text{ kHz}, \\ B_W = 400 \text{ Hz} \\ V_{CE} = 5.0 \text{ V}, \ I_C = 100 \mu\text{A}, \\ R_S = 1.0 k\Omega, \ \ f = 1.0 \text{ kHz}, \\ \end{array}$   |            | 3.0               | dB       |
| NF                   | Noise Figure                                       | $\begin{array}{l} f = 1.0 \text{ kHz} \\ I_C = 10 \text{ mA}, \ V_{CE} = 5.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \\ \hline V_{CE} = 5.0 \text{ V}, \ I_C = 10  \mu\text{A}, \\ R_S = 10  k\Omega, \ f = 1.0  k\text{Hz}, \\ B_W = 400 \text{ Hz} \\ V_{CE} = 5.0 \text{ V}, \ I_C = 100  \mu\text{A}, \\ R_S = 1.0  k\Omega, \ f = 1.0  k\text{Hz}, \\ B_W = 400 \text{ Hz} \\ \end{array}$  |            |                   |          |
| NF                   | Noise Figure                                       | $\begin{array}{l} f = 1.0 \text{ kHz} \\ I_C = 10 \text{ mA}, \ V_{CE} = 5.0 \text{ V}, \\ f = 100 \text{ MHz} \\ \\ V_{CE} = 5.0 \text{ V}, \ I_C = 10 \mu\text{A}, \\ R_S = 10 k\Omega, \ \ f = 1.0 \text{ kHz}, \\ B_W = 400 \text{ Hz} \\ V_{CE} = 5.0 \text{ V}, \ I_C = 100 \mu\text{A}, \\ R_S = 1.0 k\Omega, \ \ f = 1.0 \text{ kHz}, \\ \end{array}$   |            | 3.0               | dB<br>dB |
| NF                   | Noise Figure                                       | $\begin{array}{l} f=1.0 \text{ kHz} \\ I_C=10 \text{ mA}, \ V_{CE}=5.0 \text{ V}, \\ f=100 \text{ MHz} \\ \\ \hline V_{CE}=5.0 \text{ V}, \ I_C=10 \mu\text{A}, \\ R_S=10 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ \hline V_{CE}=5.0 \text{ V}, \ I_C=100 \mu\text{A}, \\ R_S=1.0 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ \hline V_{CE}=5.0 \text{ V}, \ I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ \hline V_{CE}=5.0 \text{ V}, \ I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ \end{array}$   |            | 3.0               | dB       |
| NF                   | Noise Figure                                       | $\begin{array}{l} f=1.0 \text{ kHz} \\ I_C=10 \text{ mA}, \ V_{CE}=5.0 \text{ V}, \\ f=100 \text{ MHz} \\ \hline \\ V_{CE}=5.0 \text{ V}, \ I_C=10 \mu\text{A}, \\ R_S=10 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, \ I_C=100 \mu\text{A}, \\ R_S=1.0 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, \ I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, \ I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, \ f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, \ I_C=100 \mu\text{A}, \\ \end{array}$  |            | 3.0               | dB<br>dB |
| NF                   | Noise Figure                                       | $\begin{array}{l} f=1.0 \text{ kHz} \\ I_C=10 \text{ mA}, V_{CE}=5.0 \text{ V}, \\ f=100 \text{ MHz} \\ \end{array}$ $\begin{array}{l} V_{CE}=5.0 \text{ V}, I_C=10 \mu\text{A}, \\ R_S=10 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=1.0 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=100 k\Omega, f=1.0 k\text{Hz}, \\ R_S=100 k\Omega, f=1.0 k\text{Hz}, \\ \end{array}$  |            | 3.0               | dB<br>dB |
| NF                   | Noise Figure                                       | $\begin{array}{l} f=1.0 \text{ kHz} \\ I_C=10 \text{ mA}, V_{CE}=5.0 \text{ V}, \\ f=100 \text{ MHz} \\ \end{array}$ $\begin{array}{l} V_{CE}=5.0 \text{ V}, I_C=10 \mu\text{A}, \\ R_S=10 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=1.0 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ \end{array}$ $\begin{array}{l} V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ \end{array}$ $\begin{array}{l} V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=100 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ \end{array}$ |            | 3.0<br>6.0<br>4.0 | dB<br>dB |
| NF                   | Noise Figure                                       | $\begin{array}{l} f=1.0 \text{ kHz} \\ I_C=10 \text{ mA}, V_{CE}=5.0 \text{ V}, \\ f=100 \text{ MHz} \\ \end{array}$ $\begin{array}{l} V_{CE}=5.0 \text{ V}, I_C=10 \mu\text{A}, \\ R_S=10 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=1.0 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=10 k\Omega, f=1.0 k\text{Hz}, \\ B_W=400 \text{ Hz} \\ V_{CE}=5.0 \text{ V}, I_C=100 \mu\text{A}, \\ R_S=100 k\Omega, f=1.0 k\text{Hz}, \\ R_S=100 k\Omega, f=1.0 k\text{Hz}, \\ \end{array}$  |            | 3.0<br>6.0<br>4.0 | dB<br>dB |

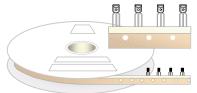
<sup>\*</sup>Pulse Test: Pulse Width  $\leq$  300  $\mu$ s, Duty Cycle  $\leq$  2.0%

#### **TO-92 Tape and Reel Data** FAIRCHILD SEMICONDUCTOR TM TO-92 Packaging Configuration: Figure 1.0 **TAPE and REEL OPTION** FSCINT Label sample See Fig 2.0 for various Reeling Styles **FSCINT** Label 5 Reels per Intermediate Box Customized F63TNR Label sample Label F63TNR LOT: CBVK741B019 QTY: 2000 SPEC: FSID: PN222N Customized D/C1: D9842 QTY1: D/C2: QTY2: N/F: F (F63TNR)3 375mm x 267mm x 375mm Intermediate Box TO-92 TNR/AMMO PACKING INFROMATION **AMMO PACK OPTION** See Fig 3.0 for 2 Ammo Packing Style Quantity EOL code Pack Options 2,000 D26Z Е 2.000 D27Z М 2,000 D74Z D75Z 2,000 **FSCINT** Unit weight = 0.22 gm Reel weight with components = 1.04 kg Ammo weight with components = 1.02 kg Max quantity per intermediate box = 10,000 units Label 5 Ammo boxes per Intermediate Box 327mm x 158mm x 135mm Customized -F63TNR Customized Label Label 333mm x 231mm x 183mm Intermediate Box (TO-92) BULK PACKING INFORMATION **BULK OPTION** See Bulk Packing DESCRIPTION QUANTITY Information table TO-18 OPTION STD NO LEAD CLIP J18Z 2.0 K / BOX Anti-static Bubble Sheets TO-5 OPTION STD NO LEAD CLIP J05Z 1.5 K / BOX FSCINT Label NO EOL TO-92 STANDARD STRAIGHT FOR: PKG 92, NO LEADCLIP 2.0 K / BOX 94 (NON PROELECTRON SERIES), 96 TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), L34Z NO LEADCLIP 2000 units per 11<mark>4mm x 102mm x 51mm</mark> EO70 box for std option Immediate Box 5 EO70 boxes per intermediate Box 530mm x 130mm x 83mm Customized Intermediate box Label FSCINT Label 10,000 units maximum per intermediate box for std option

#### TO-92 Tape and Reel Data, continued

#### **TO-92 Reeling Style** Configuration: Figure 2.0

#### Machine Option "A" (H)



Style "A", D26Z, D70Z (s/h)

# Machine Option "E" (J)

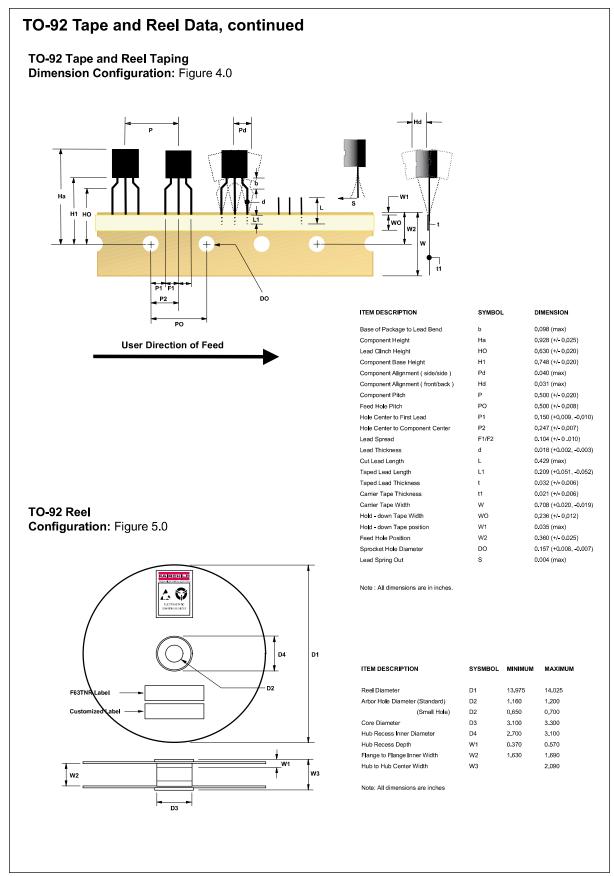
Style "E", D27Z, D71Z (s/h)

#### **TO-92 Radial Ammo Packaging** Configuration: Figure 3.0





FIRST WIRE OFF IS COLLECTOR (ON PKG. 92) ADHESIVE TAPE IS ON BOTTOM SIDE FLAT OF TRANSISTOR IS ON TOP

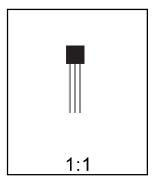


### **TO-92 Package Dimensions**



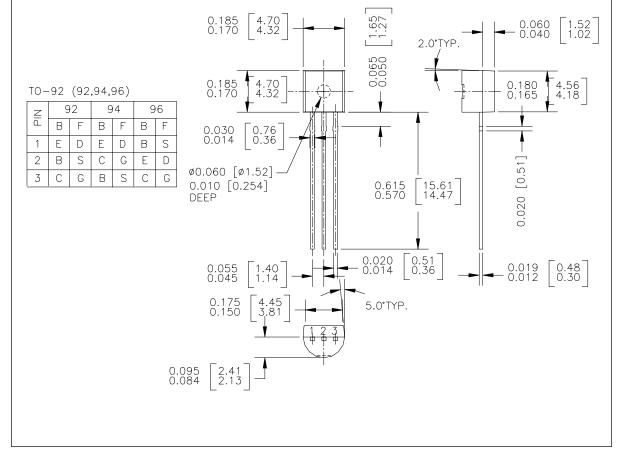
## TO-92 (FS PKG Code 92, 94, 96)

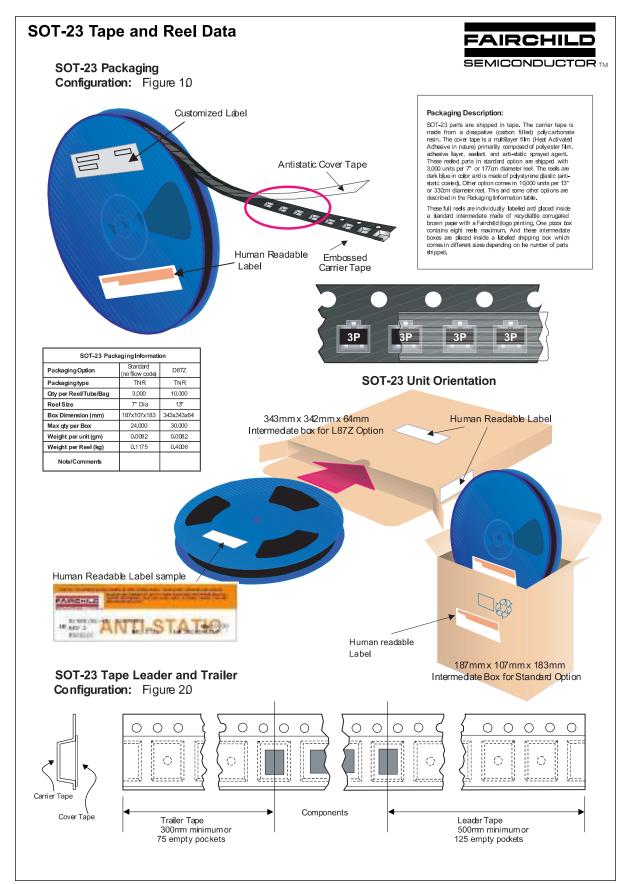




Scale 1:1 on letter size paper
Dimensions shown below are in:
inches [millimeters]

Part Weight per unit (gram): 0.1977

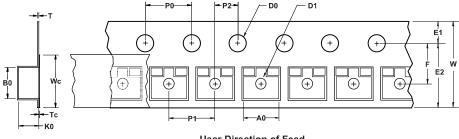




## SOT-23 Tape and Reel Data, continued

#### **SOT-23 Embossed Carrier Tape**

Configuration: Figure 3.0



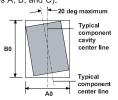
User Direction of Feed

| Dimensions are in millimeter |                 |                 |               |                 |                   |                 |             |                 |               |               |                 |                   |               |                 |
|------------------------------|-----------------|-----------------|---------------|-----------------|-------------------|-----------------|-------------|-----------------|---------------|---------------|-----------------|-------------------|---------------|-----------------|
| Pkg type                     | Α0              | В0              | w             | D0              | D1                | E1              | E2          | F               | P1            | P0            | K0              | т                 | Wc            | Тс              |
| <b>SOT-23</b> (8mm)          | 3.15<br>+/-0.10 | 2.77<br>+/-0.10 | 8.0<br>+/-0.3 | 1.55<br>+/-0.05 | 1.125<br>+/-0.125 | 1.75<br>+/-0.10 | 6.25<br>min | 3.50<br>+/-0.05 | 4.0<br>+/-0.1 | 4.0<br>+/-0.1 | 1.30<br>+/-0.10 | 0.228<br>+/-0.013 | 5.2<br>+/-0.3 | 0.06<br>+/-0.02 |

Notes: A0, B0, and K0 dimensions are determined with respect to the EIA/Jedec RS-481 rotational and lateral movement requirements (see sketches A, B, and C).



Sketch A (Side or Front Sectional View)
Component Rotation

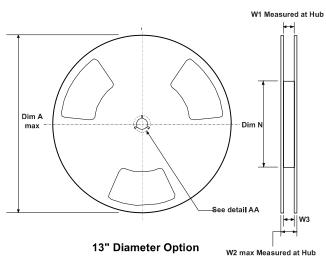


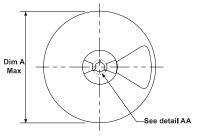
Sketch B (Top View)
Component Rotation



Sketch C (Top View)
Component lateral movement

#### SOT-23 Reel Configuration: Figure 4.0





7" Diameter Option

B Min

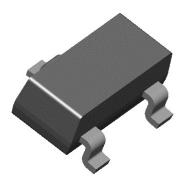
Dim D

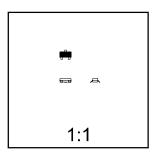
min

| Dimensions are in inches and millimeters |                |               |              |                                   |               |             |                                   |               |                             |
|--|----------------|---------------|--------------|-----------------------------------|---------------|-------------|-----------------------------------|---------------|-----------------------------|
| Tape Size                                | Reel<br>Option | Dim A         | Dim B        | Dim C                             | Dim D         | Dim N       | Dim W1                            | Dim W2        | Dim W3 (LSL-USL)            |
| 8mm                                      | 7" Dia         | 7.00<br>177.8 | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 2.165<br>55 | 0.331 +0.059/-0.000<br>8.4 +1.5/0 | 0.567<br>14.4 | 0.311 - 0.429<br>7.9 - 10.9 |
| 8mm                                      | 13" Dia        | 13.00<br>330  | 0.059<br>1.5 | 512 +0.020/-0.008<br>13 +0.5/-0.2 | 0.795<br>20.2 | 4.00<br>100 | 0.331 +0.059/-0.000<br>8.4 +1.5/0 | 0.567<br>14.4 | 0.311 - 0.429<br>7.9 - 10.9 |



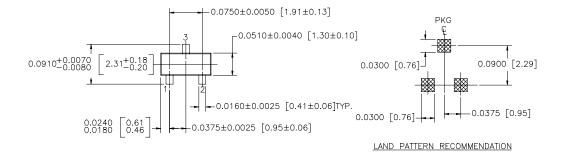
## SOT-23 (FS PKG Code 49)

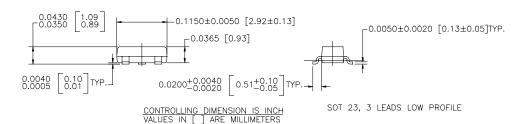




Scale 1:1 on letter size paper Dimensions shown below are in: inches [millimeters]

Part Weight per unit (gram): 0.0082





NOTE: UNLESS OTHERWISE SPECIFIED

- STANDARD LEAD FINISH 150 MICROINCHES / 3.81 MICROMETERS MINIMUM TIN / LEAD (SOLDER) ON ALLOY 42
- 2. REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE G, DATED JUL 1993

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FACT Quiet Series™ PACMAN™ SuperSOT™-6 FAST ® POP™ SuperSOT™-8

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 A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

#### PRODUCT STATUS DEFINITIONS

#### **Definition of Terms**

| Datasheet Identification | Product Status            | Definition  |  |  |  |  |
|--------------------------|---------------------------|---|--|--|--|--|
| Advance Information      | Formative or<br>In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.  |  |  |  |  |
| Preliminary              | First Production          | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design. |  |  |  |  |
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